# An Efficient Channel Model for Evaluating Wireless NoC Architectures

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Abstract—Wireless Networks-on-Chip (WiNoCs) have emerged to solve the scalability and performance bottleneck of conventional wired NoC architectures. However unlike communication in the macro-world, on-chip communication poses several constraints hence, hence there is the need for simulation and design tools that consider the effect of the wireless channel at the nanotechnology level. In this paper, we present a parameterizable channel model for WiNoCs which takes into account practical issues and constraints of the propagation medium, such as transmission frequency, operating temperature, ambient pressure and distance between the on-chip antennas. The proposed channel model demonstrates that total path loss of the wireless channel in WiNoCs suffers from not only dielectric propagation loss (DPL) but also molecular absorption attenuation (MAA) which reduces the reliability of the system.

#### I. INTRODUCTION

Wireless Network-on-Chip (NoC) has been proposed as a more promising solution to these issues and has gained the attention of many researchers in this field of study [1]. WiNoCs adopt mm-Wave enabled routers and packet or circuit switching to handle data communication in a multi-core system. Recent research shows that WiNoCs outperforms its more conventional wired counterpart [2] with low power consumption and reduced latency between remote cores. However, WiNoC is still in its infancy and several challenges are currently being addressed to facilitate its acceptance as a mainstream interconnect fabric and bridge the widening gap between computation complexity and communication efficiency for emerging SoC design [1]. Particularly, new design evaluation tools must account for the constraints imposed by the wireless interface. Compared to wireline NoCs, the critical difference is the model of wireless propagation channel in WiNoCs.

In order to more accurately simulate and evaluate the actual performance of system, a wireless propagation channel model is required. In this paper, We propose a parameterizable wireless channel model to evaluate the losses in emerging WiNoCs. Considering both line-of-sight and reflective transmission in traditional WiNoCs an on-chip reflection channel model which accounts for the transmission medium and built-in material of a practical chip is developed. Simulation results of the proposed channel model reveals that, the performance degradation due to separation distance between on-chip antennas is higher with low reliability compared to a conventional channel modeled over DPL space. We demonstrate that, the total path loss of the signal transmission consists of both dielectric propagation loss (DPL) and molecular absorption attenuation (MAA). As a second contribution of the paper, we evaluate the effects of the medium compositions within the chip package on the total

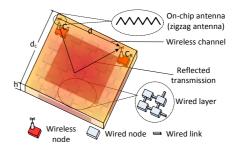


Fig. 1. System model of the communication between two cores in existing hybrid wired-wireless Network-on-Chip

noise temperature of a WiNoC. The noise temperature and path loss model caused by the molecular absorption are shown to have a significant impact on the capacity of the WiNoC. It is also observed that transmission along the wireless channel in WiNoCs is less efficient compared to conventional wireless channel model with no MAA, even when the transmission distance between two antennas is very small (less than 0.01 mm).

## II. ON-CHIP WIRELESS SIGNAL PROPAGATION

In order to understand the reduction in performance of WiNoCs due to the reliability issues of wireless channel, it is important to characterize the traditional mm-Wave transmission channel for on-chip wireless communication.

Fig. 1 illustrates a typical WiNoC architecture where two cores  $C_T$  and  $C_R$  the transmitter and receiver cores, respectively, communicate via mm-Wave channel. Here, we consider a metal cube enclosure as the package with a longest rectangular side of  $d_C$  and a height of  $h \ll d_C$ . Let  $h_T$ and  $h_R$  denote the height of the mm-Wave antennas (zigzag antennas) at  $C_T$  and  $C_R$ , respectively. The material property of the transmission medium between  $\mathcal{C}_{\mathcal{T}}$  and  $\mathcal{C}_{\mathcal{R}}$  is assumed to be time-invariant over the transmission of a data frame and changes independently from one frame to another"1". Let d denote the distance of separation between  $\mathcal{C}_{\mathcal{T}}$  and  $\mathcal{C}_{\mathcal{R}}$ . Accounting for chip floorplanning and hence in order to avoid the placement of the cores on/near the edges of the package, d should be less than  $d_{\text{max}} = d_C \sqrt{2}$ . To accurately model the wireless channel interface of existing WiNoCs, the absorption and resonance of the medium compositions within the chip

<sup>&</sup>lt;sup>1</sup>Note that there are various molecules of the gas within the material substance which may change over time. For simplicity, we consider quasistatic channel model in this work.

package should be taken into account, especially in the high frequency band of modern multi-core design. Specifically, various molecules and their isotopologues may cause molecular absorption attenuation (MAA) at various frequency bands [3]. Therefore, the signal transmission between  $\mathcal{C}_{\mathcal{T}}$  and  $\mathcal{C}_{\mathcal{R}}$  in Fig. 1 suffers from the path loss caused by not only the dielectric propagation loss (DPL) but also the MAA.

For convenience, the main notation and the well-known constants used in this paper are listed in Tables I and II, respectively.

TABLE I. SUMMARY OF NOTATION

Notation	Meaning		
d [m]	distance between two mm-Wave antennas		
$d_C$ [m]	longest rectangular side of the chip package		
d <sub>0</sub> [m]	reference distance		
h [m]	height of the chip package		
$h_T, h_R$ [m]	elevation of the mm-Wave antennas at $\mathcal{C}_{\mathcal{T}},\mathcal{C}_{\mathcal{R}},$ respectively		
f [Hz]	transmission frequency		
B [Hz]	channel bandwidth		
p [atm]	ambient pressure applied on chip		
$p_0 = 1$ atm	reference pressure		
$T_S$ [K]	system electronic noise temperature		
$T_M$ [K]	molecular absorption noise temperature		
T' [K]	other noise source temperature		
$T_p = 273.15 \text{ K}$	temperature at standard pressure		
$T_0 = 296 \text{ K}$	reference temperature		
$L_s, L_a, L$	DPL, MAA, total path loss, respectively		
$E_L, E_R$ [V/m]	line-of-sight, reflected components of E-field		
$E_0, E_T \text{ [V/m]}$	dielctric/free-space, total received E-field		
$\theta$ [rad]	phase difference between $E_L$ and $E_R$		
$P_T, P_R$ [W]	transmitted power, received power		
$G_T, G_R$	transmitter antenna gain, receiver antenna gain		
τ	transmittance of a medium		
κ	medium absorption coefficient		
(i,g)	isotopologue $i$ of gas $g$		
$\kappa^{(i,g)}$	individual absorption coefficient of $(i, g)$		
$Q^{(i,g)}$ [mol/m <sup>3</sup> ]	molecular volumetric density of $(i, g)$		
$\varsigma^{(i,g)}$ [m <sup>2</sup> /mol]	absorption cross section of $(i, g)$		
$q^{(i,g)}$ [%]	mixing ratio of $(i, g)$		
$S^{(i,g)}$ [m <sup>2</sup> Hz/mol]	line density for the absorption of $(i, g)$		
$\xi^{(i,g)} [Hz^{-1}]$	spectral line shape of $(i, g)$		
$f_c^{(i,g)}$ [Hz]	resonant frequency of $(i, g)$		
$f_{c_0}^{(i,g)}$ [Hz]	resonant frequency of $(i, g)$ at $p_0 = 1$ atm		
$v^{(i,g)} [Hz^{-1}]$	Van Vleck-Weisskopf asymmetric line shape [4]		
$\delta^{(i,g)}$ [Hz]	linear pressure shift of $(i, g)$		
$\alpha_L^{(i,g)}$ [Hz]	Lorentz half-width of $(i, g)$ [4]		
$\alpha_0$ [Hz]	broadening coefficient of air		
$\beta^{(i,g)}$ [Hz]	broadening coefficient of $(i, g)$		
ω	temperature broadening coefficient		

TABLE II. LIST OF CONSTANTS

Constant name	Symbol	Value
Avogadro constant	$\zeta_A$	$6.0221 \times 10^{23} \text{ mol}^{-1}$
Boltzmann constant	$\zeta_B$	$1.3806 \times 10^{-23} \text{ J/K}$
Gas constant	$\zeta_G$	$8.2051 \times 10^{-5} \text{ m}^3 \text{atm/K/mol}$
Light speed constant	$\zeta_L$	$2.9979 \times 10^{8} \text{ m/s}$
Planck constant	$\zeta_P$	$6.6262 \times 10^{-34} \text{ Js}$

#### III. PROPOSED WIRELESS CHANNEL MODEL

We evaluate the wireless communication fabric for existing WiNoC. Unlike the conventional channel models for the macro-world, on-chip communication introduces new constraints and challenges. Hence in order to study the effect of the wireless channel on the performance of on-chip communication, we propose a channel model that considers the physical dynamics of multi-core communication. In the proposed channel model, the total path loss of electromagnetic signal transmission from  $\mathcal{C}_{\mathcal{T}}$  to  $\mathcal{C}_{\mathcal{R}}$  within the chip package consists of DPL and MAA.

### A. Dielectric Propagation Loss (DPL)

It can be observed in Fig. 1 that the data transmission between two cores can be carried out via both direct line-of-sight (LoS) and reflected transmission. Therefore, in this paper, we develop a two-ray within-package reflection mode mm-Wave NoCs where the total received E-field  $E_T(d,f)$  [V/m] at  $\mathcal{C}_T$  consists of the LoS component  $E_L(d,f)$  [V/m] and the reflected component  $E_R(d,f)$  [V/m]. Summing up these two components, we have

$$|E_T(d,f)| = |E_L(d,f) + E_R(d,f)|$$

$$= 2\frac{E_0 d_0}{d} \sin\left(\frac{\theta(d,f)}{2}\right), \tag{1}$$

where  $E_0$  [V/m] is the dielectric E-field at a reference distance  $d_0$  [m] and  $\theta(d,f)$  [rad] is the phase difference between the two E-field components. Here,  $\theta(d,f)$  can be approximated by [5]

$$\theta(d, f) \approx \frac{4\pi h_T h_R f}{\zeta_L d},$$
 (2)

where  $h_T$  [m] and  $h_R$  [m] denote the height of the antennas at  $\mathcal{C}_T$  and  $\mathcal{C}_R$ , respectively, and  $\zeta_L=2.9979\times 10^8$  m/s is the speed of light in the vacuum.

From (1) and (2), the received power  $P_R(d, f)$  [W] at  $\mathcal{C}_R$  can be computed by

$$P_R(d,f) = \frac{|E_T(d,f)|^2 G_R \zeta_L^2}{480\pi^2 f^2}$$

$$= \frac{E_0^2 d_0^2 \zeta_L^2}{120\pi^2 d^2 f^2} G_R \sin^2 \left(\frac{2\pi h_T h_R f}{\zeta_L d}\right),$$
(3)

where  $G_R$  denotes the antenna gain at  $\mathcal{C}_R$ . Note that the equivalent isotropically radiated power (EIRP) is given by

EIRP = 
$$P_T G_T = \frac{E_0^2 d_0^2 4\pi}{120\pi} = \frac{E_0^2 d_0^2}{30},$$
 (4)

where  $P_T$  [W] and  $G_T$  denote the transmitted power and gain of the mm-Wave antenna at  $C_T$ , respectively. From (3) and (4),  $P_R$  can be given by

$$P_R(d,f) = \frac{P_T G_T G_R}{\left(\frac{2\pi df}{\zeta_L}\right)^2} \sin^2\left(\frac{2\pi h_T h_R f}{\zeta_L d}\right).$$
 (5)

Therefore, the DPL between  $\mathcal{C}_{\mathcal{T}}$  and  $\mathcal{C}_{\mathcal{R}}$  (i.e.  $L_s(f,d)$ ) is obtained by

$$L_s(f,d) = \left(\frac{2\pi df}{\zeta_L}\right)^2 \frac{1}{G_T G_R} \csc^2 \left(\frac{2\pi h_T h_R f}{\zeta_L d}\right). \quad (6)$$

#### B. Molecular Absorption Attenuation (MAA)

The transmission of electromagnetic waves at frequency f through a transmission medium of distance d introduces MAA due to various molecules within the material substance. Applying Beer-Lambert's law to atmospheric measurements, the MAA of the data transmission from  $\mathcal{C}_{\mathcal{T}}$  to  $\mathcal{C}_{\mathcal{R}}$  (i.e.  $L_a(f,d)$ ) can be determined by:

$$L_a(f,d) = \frac{1}{\tau(f,d)} = e^{\kappa(f)d},\tag{7}$$

where  $\tau(f,d)$  and  $\kappa(f)$  [m<sup>-1</sup>] are the transmittance and absorption coefficient of the medium, respectively. Here,  $\kappa(f)$  depends on the composition of the medium (i.e. particular mixture of molecules along the channel) and it is given by:

$$\kappa(f) = \sum_{i,g} \kappa^{(i,g)}(f), \tag{8}$$

where  $\kappa^{(i,g)}(f)$  [m<sup>-1</sup>] denotes the individual absorption coefficient for the isotopologue i of gas g. For simplicity in representation, the isotopologue i of gas g is hereafter denoted by (i,g).

Applying radiative transfer theory [6],  $\kappa^{(i,g)}(f)$  can be determined by

$$\kappa^{(i,g)}(f) = \frac{p}{p_0} \frac{T_p}{T_S} Q^{(i,g)} \varsigma^{(i,g)}(f), \tag{9}$$

where p [atm] is the ambient pressure applied on the designed SoC,  $T_S$  [K] is the system electronic noise temperature,  $p_0=1$  atm is the reference pressure,  $T_p=273.15$  K is the temperature at standard pressure,  $Q^{(i,g)}$  [mol/m³] is the molecular volumetric density (i.e. number of molecules per volume unit of (i,g)) and  $\varsigma^{(i,g)}(f)$  [m²/mol] is the absorption cross section of (i,g). Here,  $Q^{(i,g)}$  is obtained by the Ideal Gas Law as

$$Q^{(i,g)} = \frac{p}{\zeta_G T_S} q^{(i,g)} \zeta_A, \tag{10}$$

where  $\zeta_G=8.2051*10^{-5}~{\rm m^3atm/K/mol}$  is the Gas constant,  $\zeta_A=6.0221*10^{23}~{\rm mol^{-1}}$  is the Avogadro constant and  $q^{(i,g)}$  [%] is the mixing ratio of (i,g). In (9),  $\varsigma^{(i,g)}(f)$  is given by

$$\varsigma^{(i,g)(f)} = S^{(i,g)} \xi^{(i,g)}(f), \tag{11}$$

where  $S^{(i,g)}$  [m²Hz/mol] is the line density for the absorption of (i,g) (i.e. the absorption peak amplitude of (i,g)) and  $\xi^{(i,g)}(f)$  [Hz $^{-1}$ ] is spectral line shape of (i,g) determined by

$$\xi^{(i,g)}(f) = \frac{f}{f_c^{(i,g)}} \frac{\tanh\left(\frac{\zeta_P \zeta_L f}{2\zeta_B T_S}\right)}{\tanh\left(\frac{\zeta_P f_c^{(i,g)}}{2\zeta_B T_S}\right)} v^{(i,g)}(f), \quad (12)$$

where  $f_c^{(i,g)}$  [Hz] is the resonant frequency of (i,g),  $\zeta_P=6.6262*10^{-34}$  Js is the Planck constant,  $\zeta_B=1.3806*10^{-23}$  J/K is the Boltzmann constant and  $\upsilon^{(i,g)}(f)$  [Hz $^{-1}$ ] is the Van Vleck-Weisskopf asymmetric line shape of (i,g). In (12),

$$f_c^{(i,g)} = f_{c_0}^{(i,g)} + \delta^{(i,g)} \frac{p}{p_0}, \tag{13}$$

where  $f_{c_0}^{(i,g)}$  [Hz] is the resonant frequency of (i,g) at reference pressure  $p_0=1$  atm and  $\delta^{(i,g)}$  [Hz] is the linear pressure

shift of (i, g). Also, the Van Vleck-Weisskopf asymmetric line shape of (i, g) in (12) is given by

$$v^{(i,g)}(f) = 100\zeta_L \frac{\alpha_L^{(i,g)}}{\pi} \frac{f}{f_c^{(i,g)}} \left[ \frac{1}{(f - f_c^{(i,g)})^2 + (\alpha_L^{(i,g)})^2} + \frac{1}{(f + f_c^{(i,g)})^2 + (\alpha_L^{(i,g)})^2} \right],$$
(14)

where  $\alpha_L^{(i,g)}$  [Hz] is the Lorentz half-width of (i,g). Here,  $\alpha_L^{(i,g)}$  is computed by

$$\alpha_L^{(i,g)} = \left[ (1 - q^{(i,g)})\alpha_0 + q^{(i,g)}\beta^{(i,g)} \right] \frac{p}{p_0} \left( \frac{T_0}{T_S} \right)^{\omega}, \quad (15)$$

where  $\alpha_0$  [Hz] is the broadening coefficient of air,  $\beta^{(i,g)}$  [Hz] is the broadening coefficient of (i,g),  $T_0=296$  K is the reference temperature and  $\omega$  is the temperature broadening coefficient. Let L(f,d) denote the total path loss for signal transmission at frequency f [Hz] over distance d [m]. From (6), (7) and (8), the total path loss of the proposed channel model is

$$L(f,d) = L_s(f,d)L_a(f,d)$$

$$= \left(\frac{2\pi df}{\zeta_L}\right)^2 \frac{1}{G_T G_R} \csc^2\left(\frac{2\pi h_T h_R f}{\zeta_L d}\right) \prod_{i,g} e^{\kappa^{(i,g)}(f)d}.$$
(16)

**Remark 1** (Effectiveness of the proposed channel model). In (16), it can be shown that  $\kappa^{(i,g)} \geqslant 0 \ \forall i,g$ . This means the proposed channel model always has a higher total path loss than the conventional channel model with no MAA, and thus can represent the practical scenario as a performance benchmark.

**Remark 2** (Environment-aware channel model). The proposed channel model depends on not only the distance between two cores  $\mathcal{C}_{\mathcal{T}}$  and  $\mathcal{C}_{\mathcal{R}}$  but also the absorption of gas molecules, the temperature and the ambient pressure applied on the chip. In fact, from (9) - (15), the individual absorption coefficient for the isotopologue i of gas g (i.e.  $\kappa^{(i,g)}(f)$ ) is shown to be dependent but not monotonically varied over the frequency.

# C. Channel capacity of WiNoCs

We analyze the channel capacity of the wireless channel of WiNoCs with respect to the proposed channel model where the following observations could be made:

**Lemma 1.** The channel capacity in bits/s of a nanocommunication system between two on-chip antennas is obtained by

$$C(P_T, d) = \sum_{k=1}^{K} \Delta f \log_2 \left[ 1 + \frac{P_T G_T G_R \sin^2 \left( \frac{2\pi h_T h_R f_k}{\zeta_L d} \right)}{\zeta_B \left( \frac{2\pi d f_k}{\zeta_L} \right)^2 \Delta f} \times \frac{1}{(T_S + T_0) \prod_{i,g} e^{\kappa^{(i,g)}(f_k)d} - T_0} \right],$$

$$(17)$$

where K is the number of sub-bands in the total channel bandwidth of B [Hz],  $\Delta f = B/K$  [Hz] is the width of each sub-band and  $f_k$  [Hz] is the center frequency of the k-th sub-band.

*Proof:* As the signal-to-noise ratio (SNR) is required for evaluating the achievable capacity of a communications system, we first derive the total noise power of the nanocommunications between two mm-Wave antennas. At frequency f [Hz], the total noise temperature at  $\mathcal{C}_{\mathcal{R}}$  located at d [m] from  $\mathcal{C}_{\mathcal{T}}$  (i.e.  $T_{tot}(f,d)$  [K]) consists of the system electronic noise temperature (i.e.  $T_S$  [K]), the molecular absorption noise temperature (i.e.  $T_M(f,d)$  [K]) and other noise source temperature (i.e. T' [K]), i.e.

$$T_{tot}(f,d) = T_S + T_M(f,d) + T'.$$
 (18)

Assuming that  $T_S + T_M(f, d) \gg T' \ \forall f, d$ , we have

$$T_{tot}(f,d) \approx T_S + T_M(f,d).$$
 (19)

Here,  $T_M(f,d)$  is caused by the molecules within transmission medium, and thus can be expressed via the transmittance of the medium as

$$T_M(f,d) = T_0(1 - \tau(f,d)) = T_0 \left(1 - \prod_{i,g} e^{-\kappa^{(i,g)}(f)d}\right).$$

Substituting (20) into (19), we obtain

$$T_{tot}(f,d) \approx T_S + T_0 \left( 1 - \prod_{i,g} e^{-\kappa^{(i,g)}(f)d} \right). \tag{21}$$

The total noise power at  $\mathcal{C}_{\mathcal{R}}$  given transmission bandwidth B is therefore given by

$$P_N(d) = \zeta_B \int_B T_{tot}(f, d) df. \tag{22}$$

Note that the wireless channel for on-chip communication is highly frequency-selective and the molecular absorption noise is non-white. Therefore, we can divide the total bandwidth B into K narrow sub-bands to evaluate the capacity, in bits/s, as follows:

$$C(P_T, d) = \sum_{k=1}^{K} \Delta f \log_2 \left[ 1 + \frac{P_T}{\zeta_B L(f_k, d) T_{tot}(f_k, d) \Delta f} \right], \tag{23}$$

where  $\Delta f$  is the width of sub-band and  $f_k$  is the center frequency of the k-th sub-band. Substituting (16) and (21) into (23), we obtain (17) and thus proving the above lemma.

**Corollary 1.** When  $h_T \ll d$ ,  $h_R \ll d$ ,  $d \to 0$  and  $G_T = G_R = 1$ , the channel capacity of a nanocommunication system can be given by

$$C(P_T, d) \approx \sum_{k=1}^{K} \Delta f \log_2 \left[ 1 + \frac{P_T h_T^2 h_R^2}{\zeta_B d^4 \Delta f} \right] \times \frac{1}{T_S + (T_S + T_0)\kappa(f_k) d}.$$
(24)

*Proof*: As  $h_T \ll d$ ,  $h_R \ll d$  and  $d \to 0$ , applying Maclaurin serie [7, eq. (0.318.2)], it can be approximated that

$$\sin^2\left(\frac{2\pi h_T h_R f_k}{\zeta_L d}\right) \approx \left(\frac{2\pi h_T h_R f_k}{\zeta_L d}\right)^2,$$
 (25)

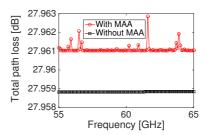


Fig. 2. Total path loss versus frequency.

$$\prod_{i,g} e^{\kappa^{(i,g)}(f_k)d} \approx 1 + \sum_{i,g} \kappa^{(i,g)}(f_k)d = 1 + \kappa(f_k)d.$$
 (26)

Substituting (25) and (26) into (17) with the assumption of  $G_T = G_R = 1$ , the corollary is proved.

It can be deduced from the above channel model that, the total path loss of electromagnetic signal transmission from between a transmitting and receiving pair has both DPL and MAA components which drastically reduce the performance and reliability of WiNoCs as will be shown latter in Section IV. Consequently, it is crucial to explore alternative communication fabric that is able transmit wireless signals with minimum losses.

#### IV. SIMULATION RESULTS

To understand the effect of the wireless channel on the total reliability of WiNoCs, the performance evaluation of the mm-wave wireless channel is carried out by investigating the channel model proposed in Section II. We compare with conventional channel model where signals are transmitted over pure air with no MAA (e.g. two-ray channel model in [5])<sup>2</sup>.

The simulation is implemented in MATLAB and the parameters of various gas compositions are obtained from the HITRAN database [3]. The impacts of the transmission medium and various channel environment parameters on the performance of mm-Wave WiNoC in terms of path loss and channel capacity are evaluated with respect to different channel modeling approaches. First, we investigate the impacts of antenna transmission frequency on the wireless channel model. Fig. 2 plots the variation of the total path loss (i.e. L) of the two considered channel models with transmission frequency at  $\mathcal{C}_{\mathcal{T}}$ . Two cores  $\mathcal{C}_{\mathcal{T}}$  and  $\mathcal{C}_{\mathcal{R}}$  (i.e.  $d_{\mathcal{C}}$ ) are implemented on a chip with a die size of  $20\text{mm}^2$  and the height (i.e. h) of 1mm. The distance between  $\mathcal{C}_{\mathcal{T}}$  and  $\mathcal{C}_{\mathcal{R}}$  (i.e. d) is set to be 0.1mm, satisfying  $d < d_C \sqrt{2}$ . Each core deploys a zigzag antennas having an elevated height of 0.02mm (i.e.  $h_T = h_R = 0.02$ mm). The transmission frequency of the antennas (i.e. f) is assumed to vary in the range from 55GHz to 65GHz. The system electronic noise temperature (i.e.  $T_S$ )

<sup>&</sup>lt;sup>2</sup>In our model, the parameterizable medium compositions consist of water vapour (which could also an effect of emerging liquid cooling technology), carbon dioxide, oxygen, nitrogen, ozone, molecular hydrogen, nitrous oxide, methane, dioxygen, nitrogen oxide, sulfur dioxide, acetylene, ethane, ethylene, methanol, hydrogen cyanide, chloromethane, hydroxyl radical, hydrogen chloride, chlorine monoxide, carbonyl sulfide, formaldehyde, hypochlorous acid, hydrogen peroxide, phosphine, carbonyl fluoride, sulfur hexafluoride, hydrogen sulfide, formic acid, hydroperoxyl radical, chlorine nitrate, nitrosonium ion, hypobromous acid, bromomethane, acetonitrile, carbon tetrafluoride, diacetylene, cyanoacetylene, carbon monosulfide, sulfur trioxide.

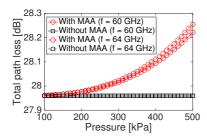


Fig. 3. Total path loss versus ambient pressure at different frequencies.

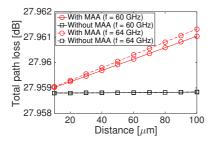


Fig. 4. Total path loss versus distance between mm-Wave antennas at different frequencies.eps

is 296 K and the ambient pressure applied on the chip (i.e. p) is 1atm.

It can be observed in Fig. 2 that the practical channel model for WiNoCs results in a higher total path loss compared to the conventional channel model. Also, the total path loss is shown to not monotonically increase at the GHz frequency band due to the fact that the MAA is caused by isotopologues of gases having various absorption coefficients at various frequencies. For example, the MAA causes a very high path loss at about 61.6GHz. These observations confirm the statements in Remarks 1 and 2 regarding the effectiveness of the proposed channel model with environment-aware property.

Taking the ambient pressure of WiNoCs into consideration, Fig. 3 plots the total path loss of various channel models versus the ambient pressure (i.e. p in kPa<sup>3</sup>) applied on the chip package. It can be seen in Fig. 3 that the total path loss in the conventional channel model is independent of the ambient pressure. However, the total path loss in the proposed channel model for practical WiNoC is shown to exponentially increase as the ambient pressure increases, which confirms the claim of the exponentially increased total path loss over the ambient pressure in Remark 2. Considering the impacts of distance between two cores on the performance of WiNoC, in Fig. 4, the total path loss of various channel models is plotted. We consider the transmission distance between  $C_T$  and  $C_R$ (i.e. d) with respect to two values of frequency f = 60 GHzand f = 64GHz. The distance d is assumed to vary in the range  $[10:100]\mu s$  and the other simulation parameters are similarly set as in Fig. 2. It can be observed that the total path loss in both the proposed and the conventional channel models increases as the distance increases, which could be straightforwardly verified from the path loss expression in (16). However, there is only a slightly increase of the path loss in  $^{3}$ Note that 1atm = 101.325kPa

the conventional model at the GHz frequency band, while such increase is shown to be significant with a much higher path loss in the proposed channel model, which is in fact caused by the consideration of the MAA to reflect the practical WiNoC. We

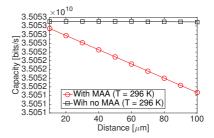


Fig. 5. Channel capacity versus distance between two antennas.

investigate the impacts of MAA in the proposed channel model on the achievable channel capacity of WiNoCs. Fig. 5 plots the channel capacity against the distance between two cores  $\mathcal{C}_{\mathcal{T}}$  and  $\mathcal{C}_{\mathcal{R}}$ . Similarly, two channel models including the proposed and the conventional models are considered for comparison and the parameters are set as in Fig. 4. The antennas are assumed to operate at frequency f=60GHz. As shown in Fig. 5, the channel capacity in the proposed channel model for the practical WiNoCs is lower than that in the conventional channel model, even when the distance between two cores is less than 0.01mm. This observation can be intuitively verified through the impacts of the transmission distance on the total path loss.

# V. CONCLUSION

## REFERENCES

- M. Agyeman, K.-F. Tong, and T. Mak, "Towards reliability and performance-aware wireless network-on-chip design," in *IEEE Interna*tional Symposium on Defect and Fault Tolerance in VLSI and Nanotechnology Systems (DFTS), 2015, pp. 205–210.
- [2] S. Deb, A. Ganguly, P. Pande, B. Belzer, and D. Heo, "Wireless noc as interconnection backbone for multicore chips: Promises and challenges," *IEEE Journal on Emerging and Selected Topics in Circuits and Systems*, vol. 2, no. 2, pp. 228–239, 2012.
- [3] L. Rothman, I. Gordon, Y. Babikov, A. Barbe, D. C. Benner, P. Bernath, M. Birk, L. Bizzocchi, V. Boudon, L. Brown, A. Campargue, K. Chance, E. Cohen, L. Coudert, V. Devi, B. Drouin, A. Fayt, J.-M. Flaud, R. Gamache, J. Harrison, J.-M. Hartmann, C. Hill, J. Hodges, D. Jacquemart, A. Jolly, J. Lamouroux, R. L. Roy, G. Li, D. Long, O. Lyulin, C. Mackie, S. Massie, S. Mikhailenko, H. Mller, O. Naumenko, A. Nikitin, J. Orphal, V. Perevalov, A. Perrin, E. Polovtseva, C. Richard, M. Smith, E. Starikova, K. Sung, S. Tashkun, J. Tennyson, G. Toon, V. Tyuterev, and G. Wagner, "The {HITRAN2012} molecular spectroscopic database," Journal of Quantitative Spectroscopy and Radiative Transfer, vol. 130, no. 0, pp. 4 50, 2013.
- [4] T. G. Kyle, Atmospheric transmission, emission and scattering. New York: Pergamon, 1991.
- [5] T. Rappaport, Wireless Communications: Principles and Practice. Prentice Hall PTR, 2001.
- [6] R. M. Goody and Y. L. Yung, Atmospheric Radiation: Theoretical basis. Oxford University Press, 1989.
- [7] I. S. Gradshteyn and I. M. Ryzhik, Table of Integrals, Series, and Products. Academic Press, 2007.